

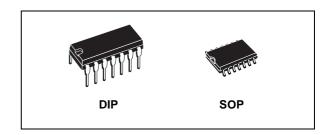


QUAD EXCLUSIVE NOR GATE

- MEDIUM-SPEED OPERATION t_{PHL} = t_{PLH} = 65ns (Typ.) at CL = 50 pF and V_{DD} = 10V
- QUIESCENT CURRENT SPECIFIED UP TO 20V
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT LEAKAGE CURRENT I₁ = 100nA (MAX) AT V_{DD} = 18V T_A = 25°C
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC JESD13B " STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIES CMOS DEVICES"



The HCF4077B is a monolithic integrated circuit fabricated in Metal Oxide Semiconductor technology available in DIP and SOP packages. The HCF4077B contains four independent exclusive NOR gates. This device provides the

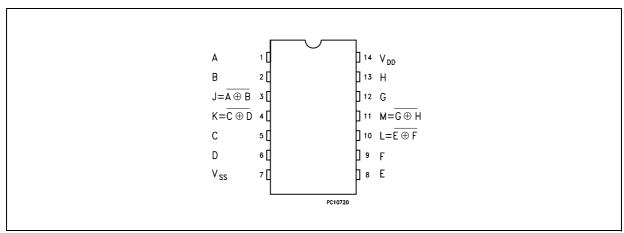


ORDER CODES

PACKAGE	TUBE	T & R
DIP	HCF4077BEY	
SOP	HCF4077BM1	HCF4077M013TR

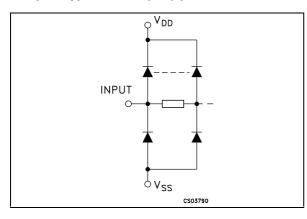
system designer with a means for direct implementation of the exclusive-NOR. For applications as logical comparators, adders/ subtractors, parity generator and checkers.

PIN CONNECTION

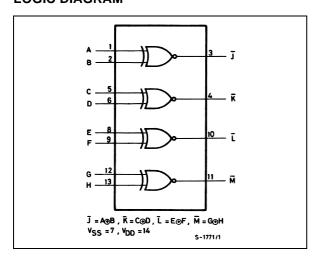


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INPUT EQUIVALENT CIRCUIT



LOGIC DIAGRAM



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1, 5, 8, 12	A, C, E, G	Data Inputs
2, 6, 9, 13	B, D, F, H	Data inputs
3, 4, 10, 11	\overline{J} , \overline{K} , \overline{L} , \overline{M}	Data Outputs
7	V _{SS}	Negative Supply Voltage
14	V_{DD}	Positive Supply Voltage

TRUTH TABLE

INP	OUTPUT	
A, C, E, G	B, D, F, H	$\overline{J}, \overline{K}, \overline{L}, \overline{M}$
L	L	Н
L	Н	L
Н	L	L
Н	Н	Н

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{DD}	Supply Voltage	-0.5 to +22	V
V _I	DC Input Voltage	-0.5 to V _{DD} + 0.5	V
l _l	DC Input Current	± 10	mA
P _D	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T _{op}	Operating Temperature	-55 to +125	°C
T _{stg}	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V_{SS} pin voltage.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{DD}	Supply Voltage	3 to 20	V
V _I	Input Voltage	0 to V _{DD}	V
T _{op}	Operating Temperature	-55 to 125	°C

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DC SPECIFICATIONS

			Test Con	dition					Value				
Symbol	Parameter	Vı	v _o	ΙΙ _Ο Ι	V _{DD}	Т	A = 25°	С	-40 to	85°C	-55 to	125°C	Unit
		(V)	(V)	(μ A)	(V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
ΙL	Quiescent Current	0/5			5		0.02	1		30		30	
		0/10			10		0.02	2		60		60	^
		0/15			15		0.02	4		120		120	μΑ
		0/20			20		0.04	20		600		600	
V_{OH}	High Level Output	0/5		<1	5	4.95			4.95		4.95		
	Voltage	0/10		<1	10	9.95			9.95		9.95		V
		0/15		<1	15	14.95			14.95		14.95		
V_{OL}	Low Level Output	5/0		<1	5		0.05			0.05		0.05	
	Voltage	10/0		<1	10		0.05			0.05		0.05	V
		15/0		<1	15		0.05			0.05		0.05	
V_{IH}	High Level Input		0.5/4.5	<1	5	3.5			3.5		3.5		
	Voltage		1/9	<1	10	7			7		7		V
			1.5/13.5	<1	15	11			11		11		
V_{IL}	Low Level Input		4.5/0.5	<1	5			1.5		1.5		1.5	
	Voltage		9/1	<1	10			3		3		3	V
			13.5/1.5	<1	15			4		4		4	
I _{OH}	Output Drive	0/5	2.5	<1	5	-1.36	-3.2		-1.15		-1.1		
	Current	0/5	4.6	<1	5	-0.44	-1		-0.36		-0.36		mA
		0/10	9.5	<1	10	-1.1	-2.6		-0.9		-0.9		ША
		0/15	13.5	<1	15	-3.0	-6.8		-2.4		-2.4		
l _{OL}	Output Sink	0/5	0.4	<1	5	0.44	1		0.36		0.36		
	Current	0/10	0.5	<1	10	1.1	2.6		0.9		0.9		mΑ
		0/15	1.5	<1	15	3.0	6.8		2.4		2.4		
l _l	Input Leakage Current	0/18	Any In	put	18		±10 ⁻⁵	±0.1		±1		±1	μΑ
CI	Input Capacitance		Any In	put			5	7.5					рF

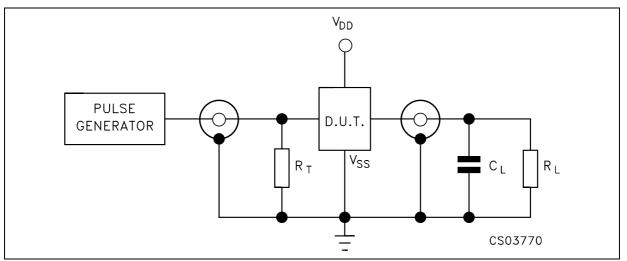
The Noise Margin for both "1" and "0" level is: 1V min. with V_{DD} =5V, 2V min. with V_{DD} =10V, 2.5V min. with V_{DD} =15V

$\textbf{DYNAMIC ELECTRICAL CHARACTERISTICS} \; (T_{amb} = 25^{\circ}C, \;\; C_{L} = 50 pF, \; R_{L} = 200 K\Omega, \;\; t_{f} = t_{f} = 20 \; ns)$

Cumbal	Davamatar		'	Unit			
Symbol	Parameter	V _{DD} (V)		Min.	Тур.	Max.	
t _{PLH} t _{PHL}	Propagation Delay Time	5			140	280	
		10			65	130	ns
		15			50	100	
t _{TLH} t _{THL}	Output Transition Time	5			100	200	
		10			50	100	ns
		15			40	80	

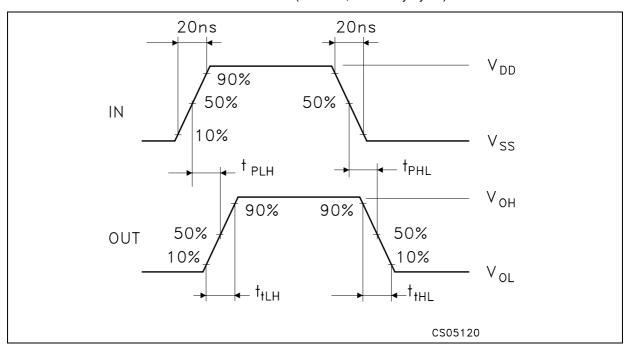
(*) Typical temperature coefficient for all V_{DD} value is 0.3 %/°C.

TEST CIRCUIT



 C_L = 50pF or equivalent (includes jig and probe capacitance) R_L = 200 $K\Omega$ R_T = Z_{OUT} of pulse generator (typically 50 Ω)

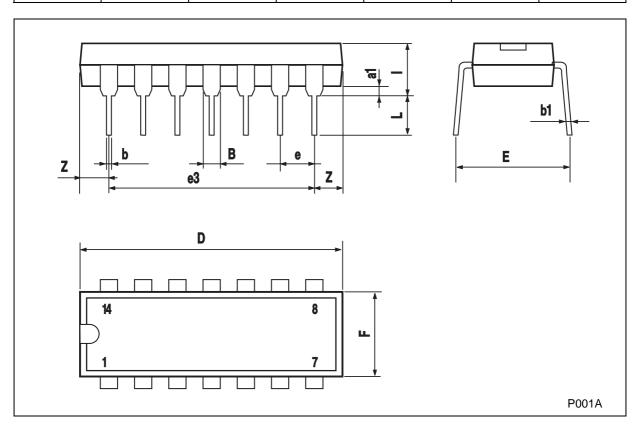
WAVEFORM: PROPAGATION DELAY TIMES (f=1MHz; 50% duty cycle)



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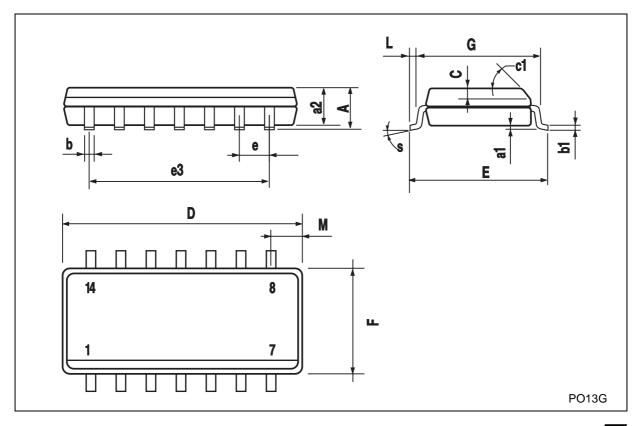
Plastic DIP-14 MECHANICAL DATA

DIM.		mm.			inch		
DIN.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
a1	0.51			0.020			
В	1.39		1.65	0.055		0.065	
b		0.5			0.020		
b1		0.25			0.010		
D			20			0.787	
E		8.5			0.335		
е		2.54			0.100		
e3		15.24			0.600		
F			7.1			0.280	
I			5.1			0.201	
L		3.3			0.130		
Z	1.27		2.54	0.050		0.100	



SO-14 MECHANICAL DATA

DIM		mm.		inch				
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
Α			1.75			0.068		
a1	0.1		0.2	0.003		0.007		
a2			1.65			0.064		
b	0.35		0.46	0.013		0.018		
b1	0.19		0.25	0.007		0.010		
С		0.5			0.019			
c1			45°	(typ.)	•			
D	8.55		8.75	0.336		0.344		
E	5.8		6.2	0.228		0.244		
е		1.27			0.050			
еЗ		7.62			0.300			
F	3.8		4.0	0.149		0.157		
G	4.6		5.3	0.181		0.208		
L	0.5		1.27	0.019		0.050		
М			0.68			0.026		
S			8° (ı	max.)				



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